

DF005S - DF10S

1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop, High Current Capability
- Surge Overload Rating to 50A Peak
- Designed for Surface Mount Application
- UL Listed Under Recognized Component Index, File Number E94661
- Lead Free Finish, RoHS Compliant (Date Code 0532+) (Note 3)

G - + A B + D E - H - C

DF-S						
Dim	Min	Max				
Α	7.40	7.90				
В	6.20	6.50				
С	0.22 0.30					
D	0.076	0.33				
E		10.40				
G	1.02	1.53				
Н	8.13	8.51				
J	2.40	2.60				
K	5.00	5.20				
L	1.00	1.20				
All Dimensions in mm						

Mechanical Data

Case: DF-S

- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 (3)
- Polarity: As marked on Case
- Marking: Type Number, See Page 3
- Weight: 0.38 grams (approximate)

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

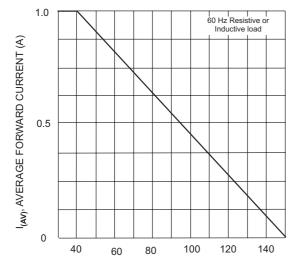
Single phase, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RMM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V _{RMS}	35	70	140	280	420	560	700	V
Average Forward Rectified Current	7 _A = 40°C	lo	1.0				Α			
Non-Repetitive Peak Forward Surge Curre single half-sine-wave superimposed on rat	nt, 8.3 ms ed load	I _{FSM}	50			А				
Forward Voltage (per element)	@ I _F = 1.0A	V _{FM}	1.1				V			
	T _A = 25°C T _A = 125°C		10 500				μΑ			
I ² t Rating for Fusing (t<8.3ms)		I ² t				10.4				A ² s
Typical Total Capacitance (per element) (N	lote 1)	C _T				25				pF
Typical Thermal Resistance, Junction to A (Note 2)	mbient	$R_{\theta JA}$				40				°C/W
Operating and Storage Temperature Rang	е	Tj, TSTG			-	65 to +15	0			°C

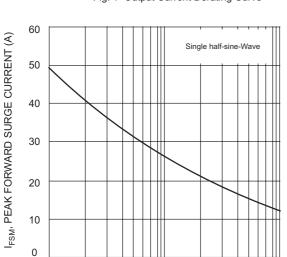
Notes

- 1. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.
- 2. Thermal resistance, junction to ambient, measured on PC board with 5.0mm² (0.03mm thick) land areas.
- 3. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see *EU Directive Annex Notes 5 and 7*.



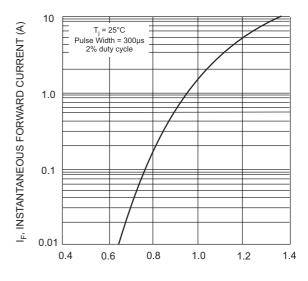


T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Output Current Derating Curve

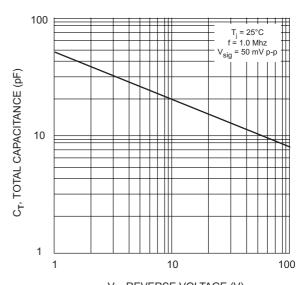


NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current

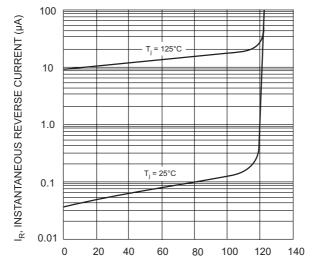
10



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typ Forward Characteristics (per element)



 $\label{eq:VR} \mbox{$V_R$, REVERSE VOLTAGE (V)}$ Fig. 4 Typical Total Capacitance (per element)



100

PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typ Reverse Characteristics (per element)



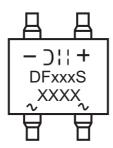
Ordering Information (Note 4)

Device*	Packaging	Shipping
DFxS	DF-S	50 Per Tube
DFxS-T	DF-S	1500/Tape & Reel, 13-inch

^{*} x = Device type, e.g. DF005S or DF10S, etc.

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Oll = Manufacturers' code marking
DFxxxS = Product type marking code, ex: DF10S
YWW = Date code marking
Y = Last digit of year ex: 2 for 2002
WW = Week code 01 to 52

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.